



0.02

3A TrenchSBR TRENCH SUPER BARRIER RECTIFIER

Product Summary (@ T		_A = +25 ℃)		
V _{RRM} (V)	I _O (A)	V _{F(MAX)} (V)	I _{R(MAX)} (mA)	

0.49

Description and Applications

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Packaged in the compact U-DFN3030-8 package, the TrenchSBR SBRT3M30LP provides excellent low reverse leakage stability at high temperatures. It is ideal for use in low voltage, high frequency inverters, as well as freewheeling and polarity protection applications.

- AC-DC Adaptors/Chargers
- **DC-DC Converters**
- **Bypass Diode**
- Boost Diode

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- **Blocking Diode**
- **Recirculating Diode**

Features and Benefits

- Low Power Loss, High Efficiency
- Low Reverse Leakage Current
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

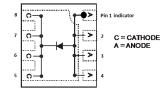
Mechanical Data

- Case: U-DFN3030-8
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe; Solderable per MIL-STD-202, Method 208@4
- Polarity: See Diagram
- Weight: 0.0172 grams (Approximate)

U-DFN3030-8



Bottom View



Top View Schematic and Pin Configuration

Ordering Information (Note 4)

Part Number Qualification Case Packaging SERT3M20LP.7 Commercial LLDEN2020.8 2.000/Tapp.8, Papel						
SPDT2M20LP 7 Commorgial LLDEN2020 8 2 000/Tapo 8 Pool	Part Number		Case	Packaging		
	SBRT3M30LP-7	Commercial	11-DEN3030-8	3 000/Tape & Reel		

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



T3M30 = Product Marking Code YYWW = Date Code Marking YY = Last Digit of Year (ex: 15 for 2015) WW = Week Code $(01 \sim 53)$



Maximum Ratings (@T_A = +25 °C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	30	v
RMS Reverse Voltage	V _{R(RMS)}	21	V
Average Rectified Output Current	lo	3.0	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	30	А

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Typical Thermal Resistance Junction to Case	(Note 5)	$R_{\theta JC}$	15	°C/W
Typical Thermal Resistance Junction to Ambient Air	(Note 5)	R _{θJA}	152	°C/W
Typical Thermal Resistance Junction to Case	(Note 6)	$R_{\theta JC}$	7	°C/W
Typical Thermal Resistance Junction to Ambient Air	(Note 6)	$R_{\theta JA}$	76	°C/W
Operating and Storage Temperature Range		TJ, T _{STG}	-65 to +175	°C

Electrical Characteristics (@T_A = +25 °C, unless otherwise specified.)

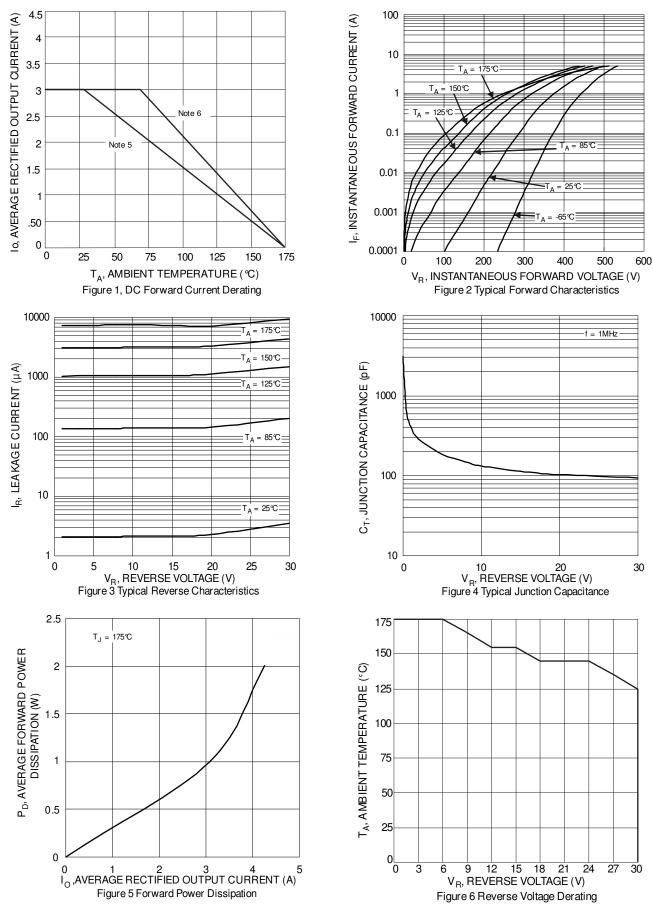
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 7)	V _{(BR)R}	30	—	_	V	$I_{R} = 0.02 mA$
Forward Voltage	V _F	_	0.45 0.43	0.49	V	$I_F = 3.0A, T_a = +25 \degree C$ $I_F = 3.0A, T_a = +125 \degree C$
Reverse Current (Note 7)	I _R	_	0.005	0.02	mA	T _J = +25 ℃, V _R = 30V
Total Capacitance	Ст	_	100	_	pF	f = 1MHz, V _R = 30V
Reverse Recovery Time	t _{rr}	_	16	—	ns	I _F =0.5A, I _R =1.0A, I _{RR} =0.25A

Notes: 5. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com. $T_A = +25 \,^{\circ}\text{C}$.

PCB with 1-inch sq. Copper pad, 2oz.
Short duration pulse test used to minimize self-heating effect.



SBRT3M30LP

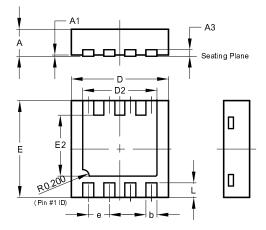


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Package Outline Dimensions

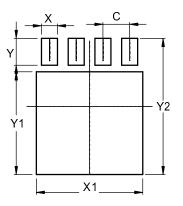
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



U-DFN3030-8					
Dim	Min	Max	Тур		
Α	0.57	0.63	0.60		
A1	0	0.05	0.02		
A3	-	-	0.15		
b	0.29	0.39	0.34		
D	2.90	3.10	3.00		
D2	2.19	2.39	2.29		
е	-	-	0.65		
Е	2.90	3.10	3.00		
E2	1.64	1.84	1.74		
L	0.30	0.60	0.45		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value	
Billionoliono	(in mm)	
С	0.650	
X	0.390	
X1	2.590	
Y	0.650	
Y1	2.490	
Y3	3.300	



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